

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _C = +25°C
40V	$15m\Omega @ V_{GS} = 10V$	43.6A
	25mΩ @ V _{GS} = 4.5V	33A

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

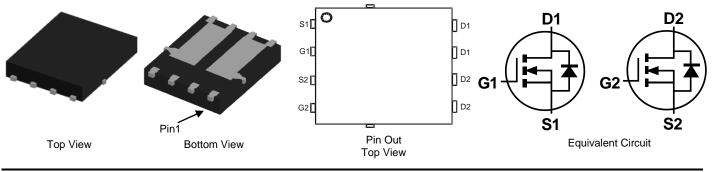
- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMTH4014LPDQ)

Mechanical Data

- Case: PowerDI[®]5060-8 (Type C)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

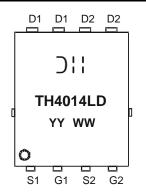
	Part Number	Case	Packaging		
DMTH4014LPD-13		PowerDI5060-8 (Type C)	2,500/Tape & Reel		
Notes:	Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.				

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See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

<1000ppm antimony compounds. 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



) || = Manufacturer's Marking TH4014LD = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 18 = 2018) WW = Week (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	40	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current (Note 5)	T _C = +25°C T _C = +100°C	I _D	43.6 30.8	A
Continuous Drain Current (Note 6)	T _A = +25°C T _A = +100°C	I _D	10.6 7.5	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	75	A	
Maximum Continuous Body Diode Forward Current (Note 6)	ls	36	A	
Avalanche Current, L = 0.3mH	I _{AS}	11.7	A	
Avalanche Energy, L = 0.3mH	E _{AS}	20.5	mJ	

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	PD	2.41	W	
Thermal Resistance, Junction to Ambient (Note 5)	R _{θJA}	62.6	°C/W	
Total Power Dissipation (Note 6)	PD	42.8	W	
Thermal Resistance, Junction to Case (Note 6)	R _{ejc}	3.5	°C/W	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

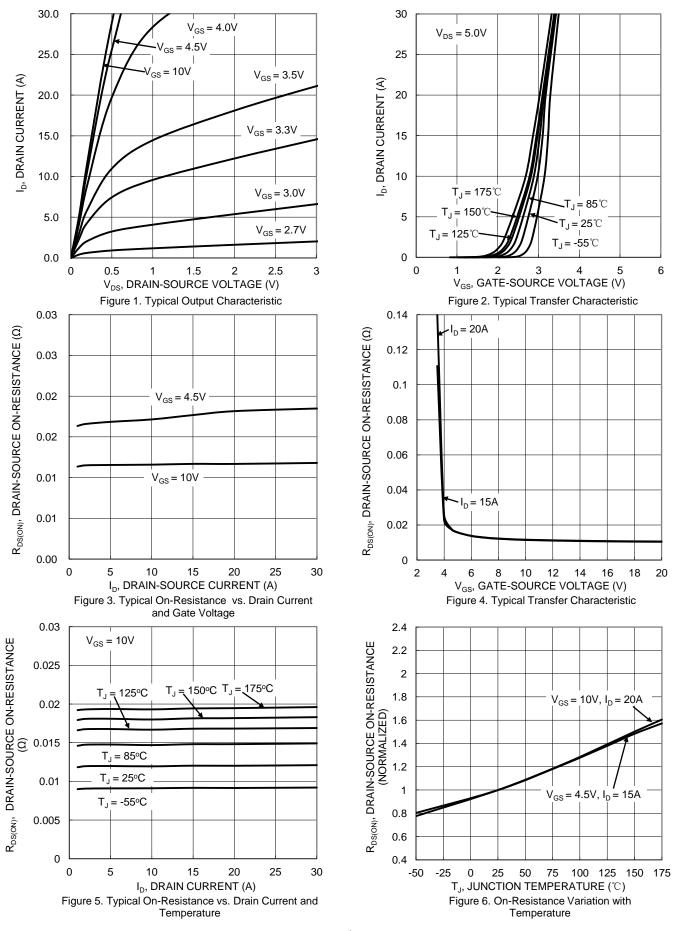
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						-	
Drain-Source Breakdown Voltage	BV _{DSS}	40	—	—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	_	—	1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	1	1.3	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Paaraa	_	11.8	15	mΩ	$V_{GS} = 10V, I_D = 20A$	
	R _{DS(ON)}	_	17.9	25	11152	$V_{GS} = 4.5V, I_D = 15A$	
Diode Forward Voltage	V _{SD}	_	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	_	733	—	pF	V _{DS} = 20V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	_	235	_	pF		
Reverse Transfer Capacitance	Crss	_	24	_	pF		
Gate Resistance	R _g	_	1.3	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	5.2	—	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	_	10.2	_	nC)/ 20)/ I= 20A	
Gate-Source Charge	Q _{gs}	_	1.5	_	nC	$V_{DS} = 20V, I_D = 20A$	
Gate-Drain Charge	Q _{gd}	_	3.1	_	nC	1	
Turn-On Delay Time	t _{D(ON)}	—	3.5	—	ns		
Turn-On Rise Time	t _R	—	5.7	—	ns	$V_{DD} = 20V, V_{GS} = 10V,$ $R_G = 1.6\Omega, I_D = 20A$	
Turn-Off Delay Time	t _{D(OFF)}	_	8.7	_	ns		
Turn-Off Fall Time	t _F	_	1.8	—	ns		
Body Diode Reverse Recovery Time	t _{RR}	—	11.9	—	ns	L 150 di/dt 1000/	
Body Diode Reverse Recovery Charge	Q _{RR}	—	9.28	_	nC	I _F = 15A, di/dt = 400A/μs	

5. Device mounted on FR-4 substrate PC board, 2oz. copper, with thermal bias to bottom layer 1inch square copper plate. Notes:

6. Thermal resistance from junction to soldering point (on the exposed drain pad).7. Short duration pulse test used to minimize self-heating effect.8. Guaranteed by design. Not subject to product testing.

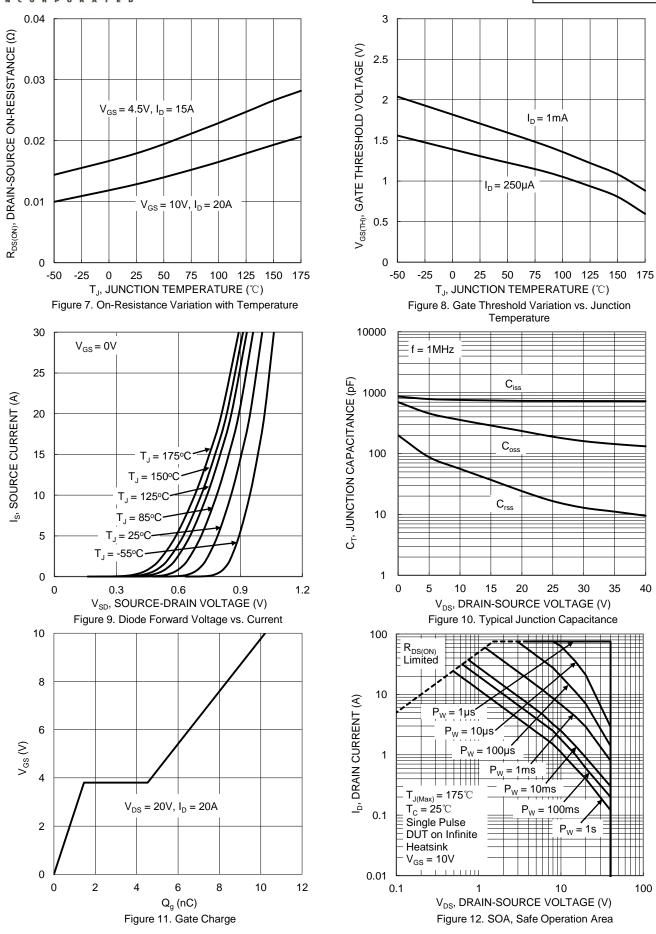


DMTH4014LPD



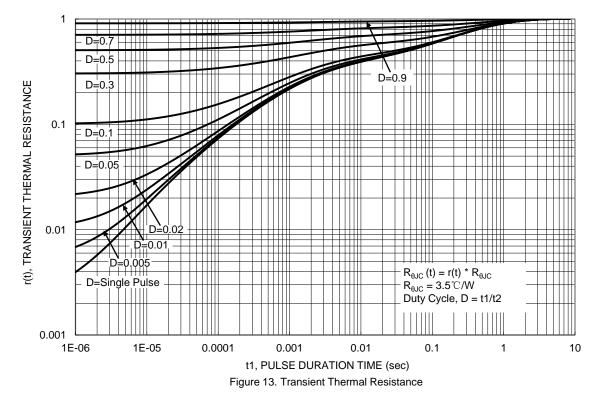






DMTH4014LPD Document number: DS40343 Rev. 2 - 2



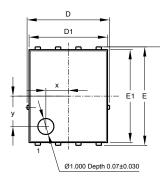


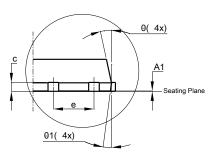


Package Outline Dimensions

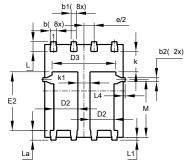
Please see http://www.diodes.com/package-outlines.html for the latest version.

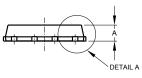
PowerDI5060-8 (Type C)





DETAIL A



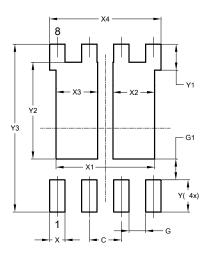


Po	PowerDI5060-8 (Type C)						
Dim	Min	Тур					
Α	0.90	1.10	1.00				
A1	0	0.05	0.02				
b	0.33	0.51	0.41				
b1	0.300	0.366	0.333				
b2	0.20	0.35	0.25				
С	0.23	0.33	0.277				
D	!	5.15 BSC)				
D1	4.85	4.95	4.90				
D2	1.40	1.60	1.50				
D3	-	3.98					
Е	6.15 BSC						
E1	5.75	5.85	5.80				
E2	3.56 3.76		3.66				
е	1.27BSC						
k	-	-	1.27				
k1	0.56	-	-				
L	0.51	0.71	0.61				
La	0.51	0.71	0.61				
L1	0.05	0.20	0.175				
L4	-	-	0.125				
М	3.50	3.71	3.605				
х	-	-	1.400				
У	-	-	1.900				
θ	10°	12°	11°				
θ1	6°	8°	7°				
AI	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (Type C)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	3.910		
X2	1.650 1.650		
X3			
X4	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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